

Mid-Infrared (MIR) Photodiode

<u>1.8</u> - 3.8 μm

Lms36PD-03-R-PA and Lms36PD-03-RW-PA

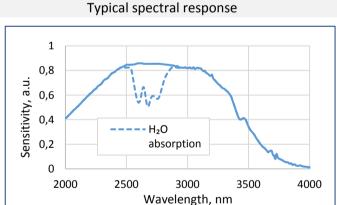
Device parameters	Symbol	Value	Units	
Sensitive area diameter	d	0.3	mm	
Storage temperature	T _{stg}	-50+60*	°C	
Operating temperature	T _{opr}	0+50*	°C	
Reverse voltage	operates unbiased			



*PD design for higher storage/operating temperature is available under request

Photodiode parameters	Conditions	Symbol	Value	Units
Cut-off wavelength	T = 25 °C	λ_{cut}	3.7 - 3.8	μm
Max. sensitivity range (>80%)	T = 25 °C	λ_p	2.45 - 3.30	μm
Dark current	T = 25 °C; V _r = 1 V	Ι _d	50 - 600	μΑ
Shunt resistance	T = 25 °C; V _r = 10 mV	R _{sh}	0.2 - 0.6	kΩ
Capacitance	T = 25 °C; $\lambda = \lambda_p$	С	200 - 300	pF
Sensitivity	T = 25 °C; $\lambda = \lambda_p$	S	0.7 - 0.8	A/W
Noise equivalent power	T = 25 °C; $\lambda = \lambda_p$	NEP	(6-13)*10 ⁻¹²	W/Hz ^{1/2}
Detectivity	T = 25 °C; $\lambda = \lambda_p$	D*	(2-4)*10 ¹⁰	cm [·] Hz ^{1/2} ·W ⁻¹

Photodiodes Lms36PD-03 series are fabricated from narrow band-gap InAsSbP/InAs-based heterostructures lattice matched to InAs substrate.



Typical current-voltage characteristic

-500

Voltage, mV

Current, mA

-1000

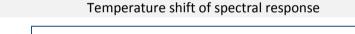
200

150

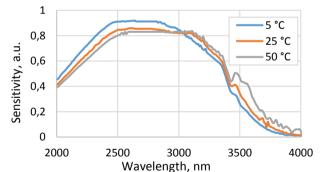
100

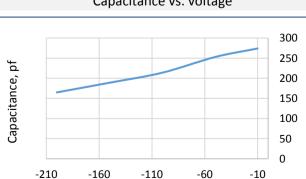
50

0 -50



All specifications are for photodiode operation at 25°C unless otherwise stated





Voltage, mV

Capacitance vs. voltage

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500

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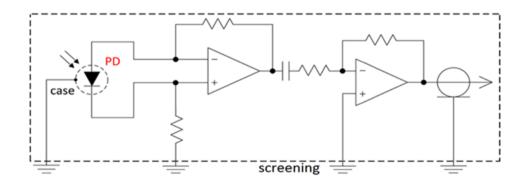


Packages	Model
TO-18 with a cap without a glass window	Lms36PD-03
TO-18 with a parabolic reflector without a glass window	Lms36PD-03-R
TO-18 with a parabolic reflector with a glass window	Lms36PD-03-RW
TO-5 with a built-in thermocooler and thermoresistor, covered by a cap with a glass window	Lms36PD-03-TEM
TO-5 with a built-in thermocooler and thermoresistor, covered by a parabolic reflector with a glass window	Lms36PD-03-TEM-R
PD with a built-in preamplifier; TO-18 with a parabolic reflector without a window in an aluminum tube	Lms36PD-03-R-PA
PD with a built-in preamplifier; TO-18 with a parabolic reflector with a window in an aluminum tube	Lms36PD-03-RW-PA

Operation mode of photodiode with a built-in preamplifier

Photodiode models with LMSNT preamplifier (-PA) work in photovoltaic mode. Current generated by photodiode is amplified and converted by preamplifier into voltage signal. There is straight correspondence between PD current and resulting output voltage. The signal converted by preamplifier will have the same form, frequency and pulse duration as the photocurrent signal from photodiode. Current into voltage conversion coefficient is constant and depends on given photodiode.

NOTE! Preamplifier is typically tuned for operation with an LED emitter working in a pulse mode with 0.5 kHz frequency and 20 µs pulse duration. Tuning for other operation modes is available under special request.



Power input voltage: +5 V, stabilized;

Connections:

The output of PD with a built-in preamplifier has four wires:

- "+" power input (to the "+" of the power output terminal block of the SDM synchronous detector);
- "-" power input (to the "-" of the power output terminal block of the SDM synchronous detector);
- output photodiode signal (to the "-" of the signal input terminal block of the SDM synchronous detector);

• output photodiode signal (to the "+" of the signal input terminal block of the SDM synchronous detector).

For the proper connection mind colours of the wires pointed in the technical data provided with the photodiode.

IMPORTANT CAUTIONS:

- please check your connection circuit before turning on the PD;
- please do not connect the PD to the multimeter.

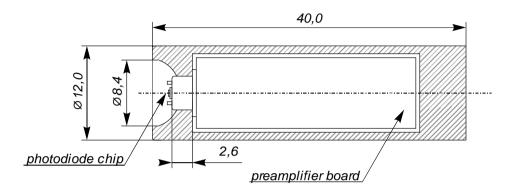
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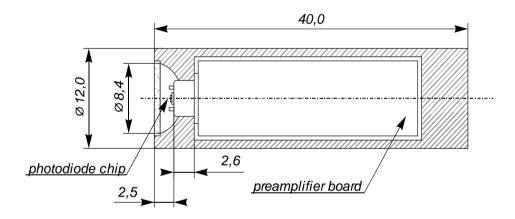


Technical Drawings

Lms36PD-03-R-PA



Lms36PD-03-RW-PA



Related products:

- LEDs sources of mid-infrared radiation;
- **SDM** synchronous detector for PD models with preamplifiers Lms MIR PD-XX-R-PA and Lms MIR PD-XX-RW-PA. SDM synchronous detector measures the voltage signal from the output of photodiode preamplifier and converts it to the DC voltage signal proportional to amplitude of voltage from input.

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